

**4-PIN SOP, 1.0  $\Omega$  LOW ON-STATE RESISTANCE  
1-ch Optical Coupled MOS FET****DESCRIPTION**

The PS7214-1A is a low on-state resistance solid state relay containing a GaAs LED on the input side and MOS FETs on the output side.

It is suitable for PLC, etc. because of its large continuous load current and low on-state resistance.

**FEATURES**

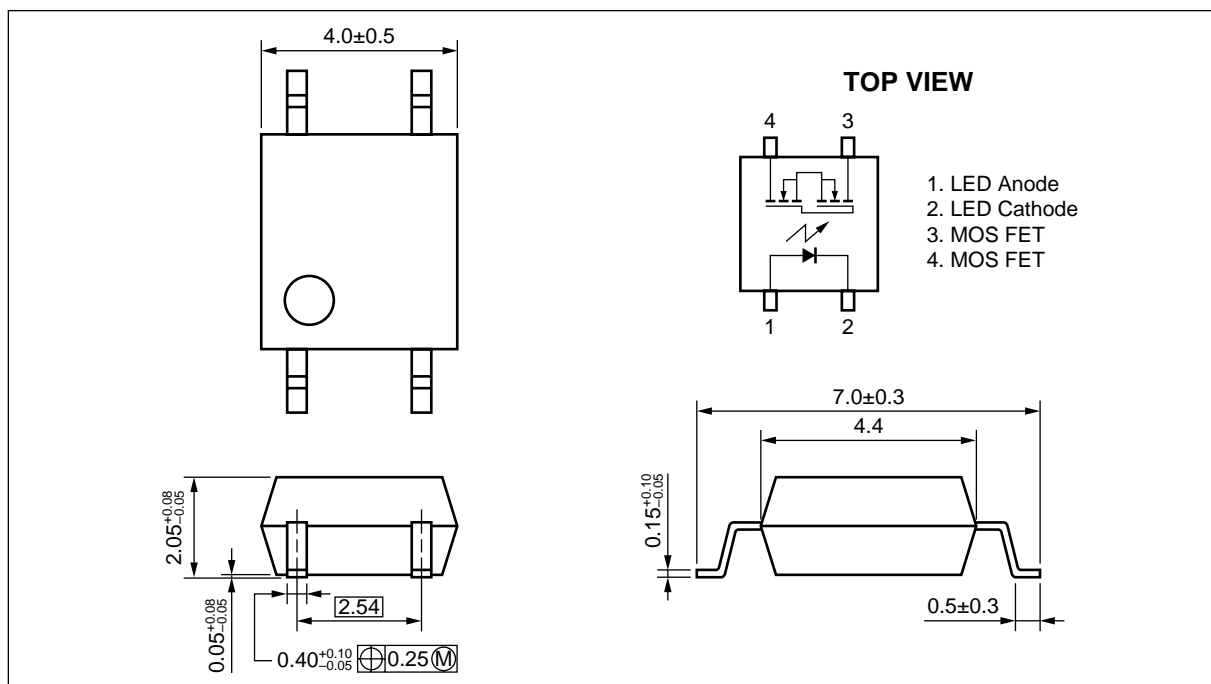
- Low on-state resistance ( $R_{on} = 1.0 \Omega$  TYP.)
- Large continuous load current ( $I_L = 400$  mA)
- 1 channel type (1 a output)
- Designed for AC/DC switching line changer
- Small and thin package (4-pin SOP, Height = 2.1 mm)
- High isolation voltage ( $BV = 1\,500$  V r.m.s.)
- Low offset voltage
- Ordering number of taping product: PS7214-1A-E3, E4, F3, F4

**APPLICATIONS**

- Measurement equipment
- FA equipment

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

PACKAGE DIMENSIONS (Unit: mm)



★ ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number <sup>*1</sup>
PS7214-1A	4-pin SOP	Magazine case 100 pcs	PS7214-1A
PS7214-1A-E3		Embossed Tape 900 pcs/reel	
PS7214-1A-E4			
PS7214-1A-F3		Embossed Tape 3 500 pcs/reel	
PS7214-1A-F4			

\*1 For the application of the Safety Standard, following part number should be used.

**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25 °C, unless otherwise specified)**

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	I <sub>F</sub>	50	mA
	Reverse Voltage	V <sub>R</sub>	5.0	V
	Power Dissipation	P <sub>D</sub>	50	mW
	Peak Forward Current <sup>*1</sup>	I <sub>FP</sub>	1	A
MOS FET	Break Down Voltage	V <sub>L</sub>	100	V
	Continuous Load Current	I <sub>L</sub>	400	mA
	Pulse Load Current <sup>*2</sup> (AC/DC Connection)	I <sub>LP</sub>	0.8	A
	Power Dissipation	P <sub>D</sub>	300	mW
Isolation Voltage <sup>*3</sup>		BV	1 500	Vr.m.s.
Total Power Dissipation		P <sub>T</sub>	350	mW
Operating Ambient Temperature		T <sub>A</sub>	−40 to +85	°C
Storage Temperature		T <sub>stg</sub>	−40 to +100	°C

\*1 PW = 100 μs, Duty Cycle = 1 %

\*2 PW = 100 ms, 1 shot

\*3 AC voltage for 1 minute at T<sub>A</sub> = 25 °C, RH = 60 % between input and output

RECOMMENDED OPERATING CONDITIONS ( $T_A = 25\text{ }^\circ\text{C}$ )

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	$I_F$	2	10	20	mA
LED Off Voltage	$V_F$	0		0.5	V

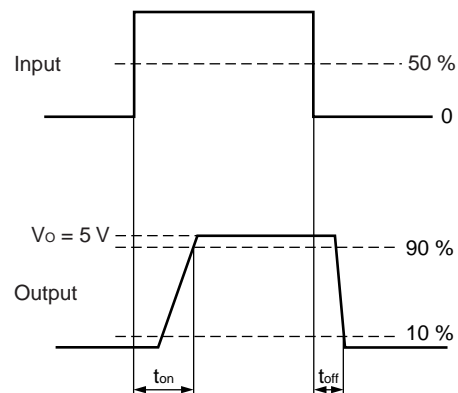
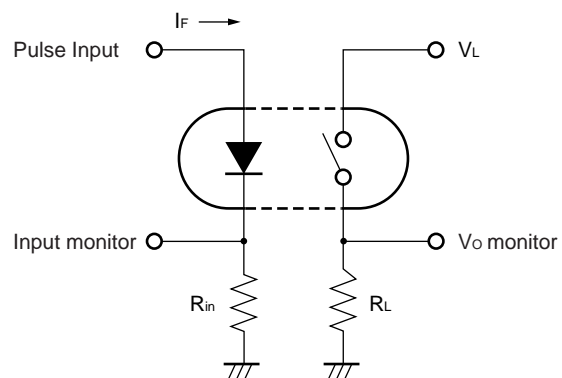
ELECTRICAL CHARACTERISTICS ( $T_A = 25\text{ }^\circ\text{C}$ )

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	$V_F$	$I_F = 10\text{ mA}$		1.2	1.4	V
	Reverse Current	$I_R$	$V_R = 5\text{ V}$			5.0	$\mu\text{A}$
MOS FET	Off-state Leakage Current	$I_{\text{Leak}}$	$V_D = 100\text{ V}$			1.0	$\mu\text{A}$
	Output Capacitance	$C_{\text{out}}$	$V_D = 0\text{ V}, f = 1\text{ MHz}$		120		pF
Coupled	LED On-state Current	$I_{\text{Fon}}$	$I_L = 400\text{ mA}$			2.0	mA
	On-state Resistance	$R_{\text{on}}$	$I_F = 10\text{ mA}, I_L = 400\text{ mA}, t \leq 10\text{ ms}$		1.0	1.2	$\Omega$
	Turn-on Time <sup>*1</sup>	$t_{\text{on}}$	$I_F = 10\text{ mA}, V_O = 5\text{ V}, R_L = 500\text{ }\Omega,$ $PW \geq 10\text{ ms}$		1.3	2.0	ms
	Turn-off Time <sup>*1</sup>	$t_{\text{off}}$			0.1	1.0	
	Isolation Resistance	$R_{\text{I-O}}$	$V_{\text{I-O}} = 1.0\text{ kV}_{\text{DC}}$	$10^9$			$\Omega$
	Isolation Capacitance	$C_{\text{I-O}}$	$V = 0\text{ V}, f = 1\text{ MHz}$		0.5		pF

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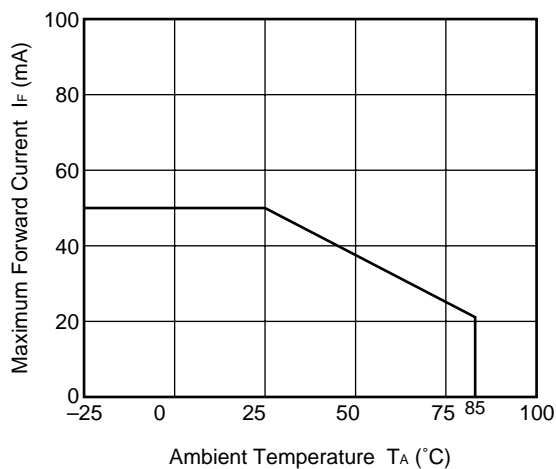
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\*1 Test Circuit for Switching Time

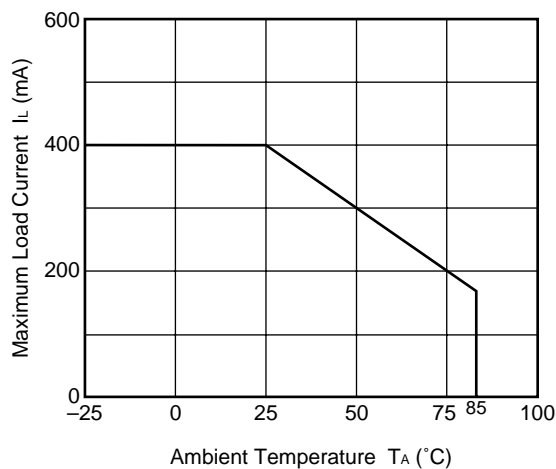


★ TYPICAL CHARACTERISTICS ( $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

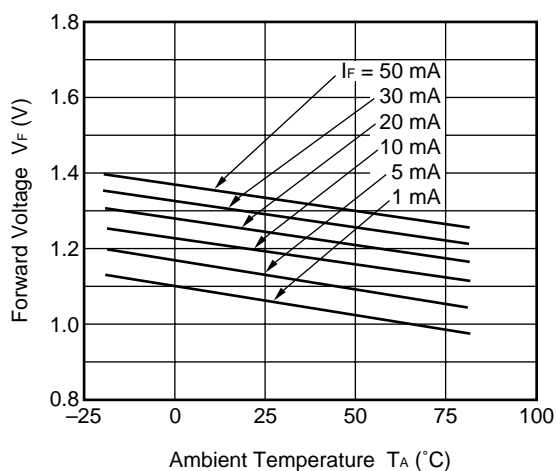
MAXIMUM FORWARD CURRENT vs.  
AMBIENT TEMPERATURE



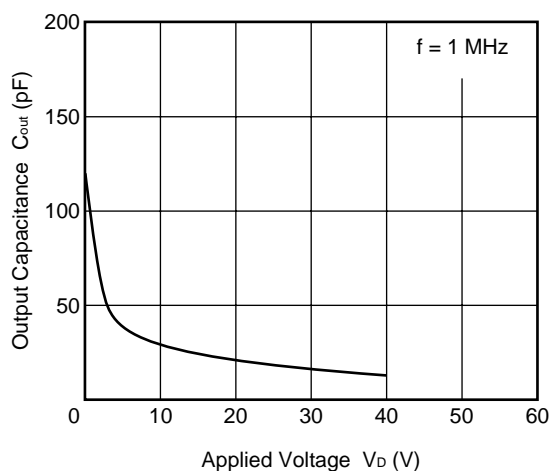
MAXIMUM LOAD CURRENT vs.  
AMBIENT TEMPERATURE



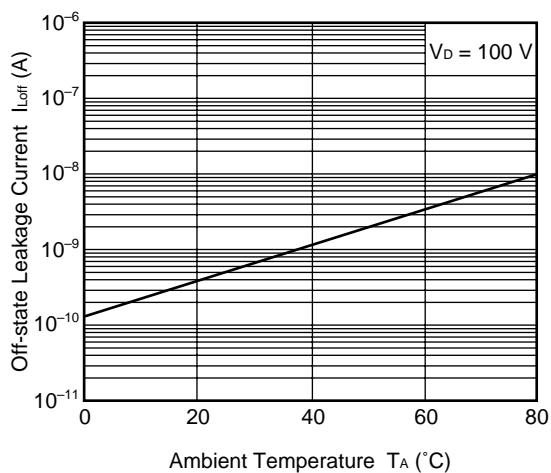
FORWARD VOLTAGE vs.  
AMBIENT TEMPERATURE



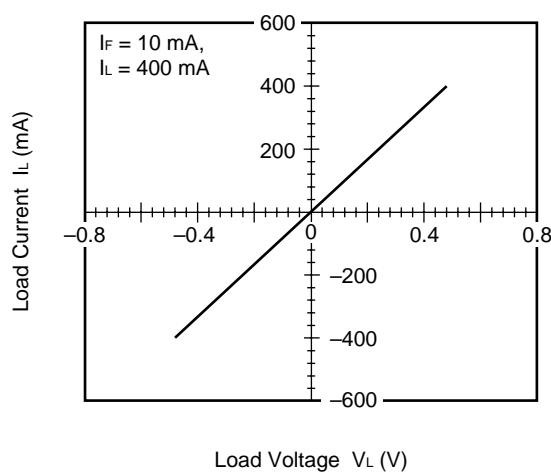
OUTPUT CAPACITANCE vs.  
APPLIED VOLTAGE



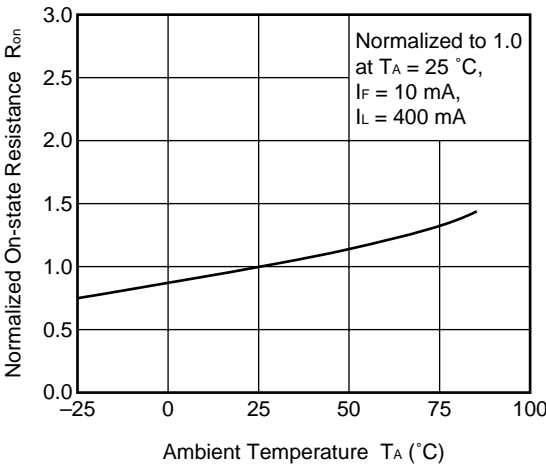
OFF-STATE LEAKAGE CURRENT vs.  
AMBIENT TEMPERATURE



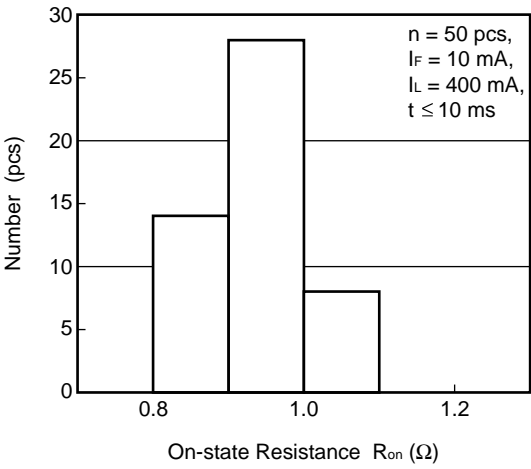
LOAD CURRENT vs. LOAD VOLTAGE



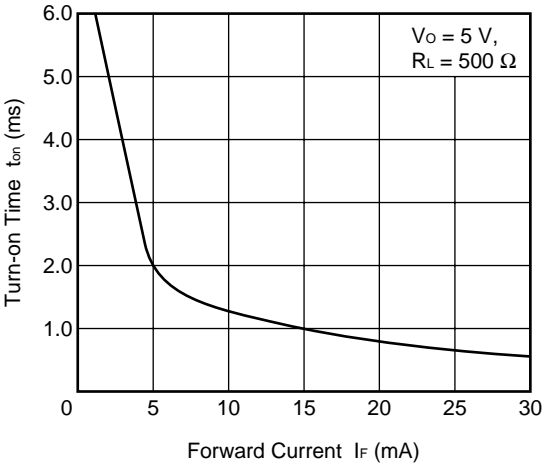
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



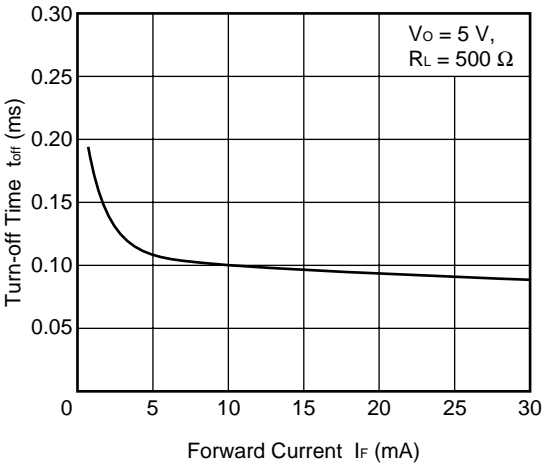
ON-STATE RESISTANCE DISTRIBUTION



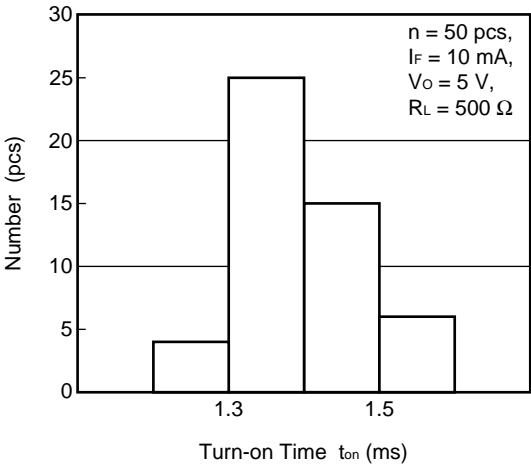
TURN-ON TIME vs. FORWARD CURRENT



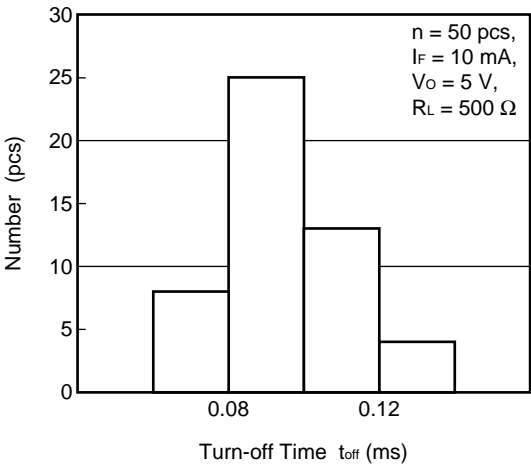
TURN-OFF TIME vs. FORWARD CURRENT



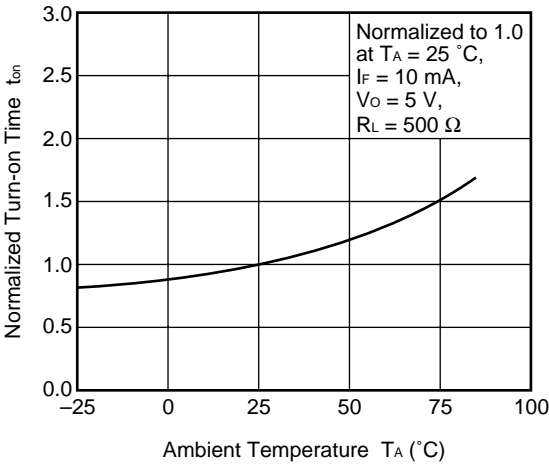
TURN-ON TIME DISTRIBUTION



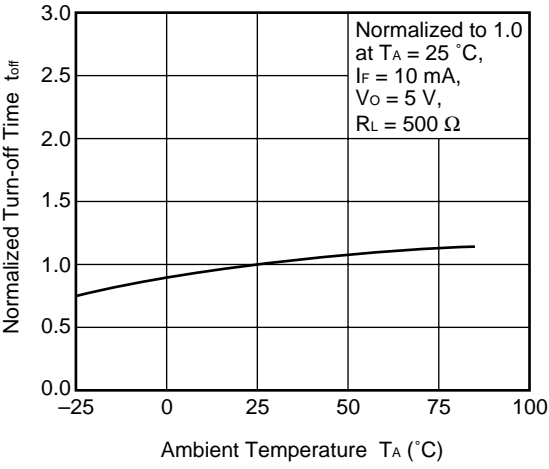
TURN-OFF TIME DISTRIBUTION



NORMALIZED TURN-ON TIME vs.  
AMBIENT TEMPERATURE



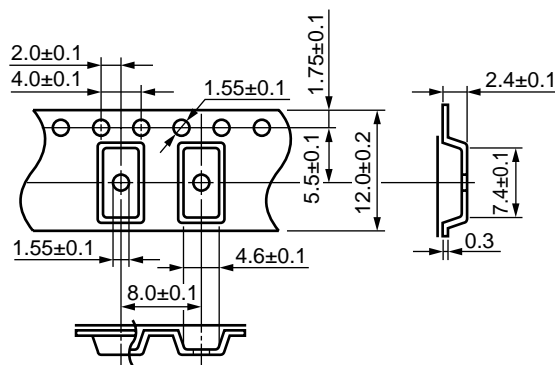
NORMALIZED TURN-OFF TIME vs.  
AMBIENT TEMPERATURE



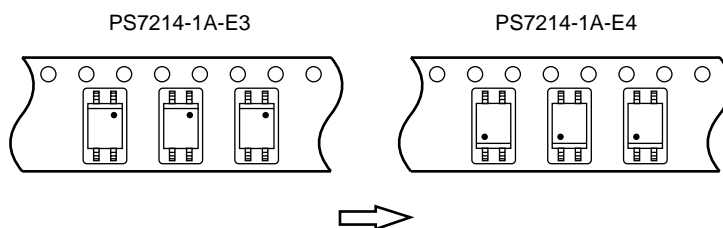
**Remark** The graphs indicate nominal characteristics.

★ TAPING SPECIFICATIONS (in millimeters)

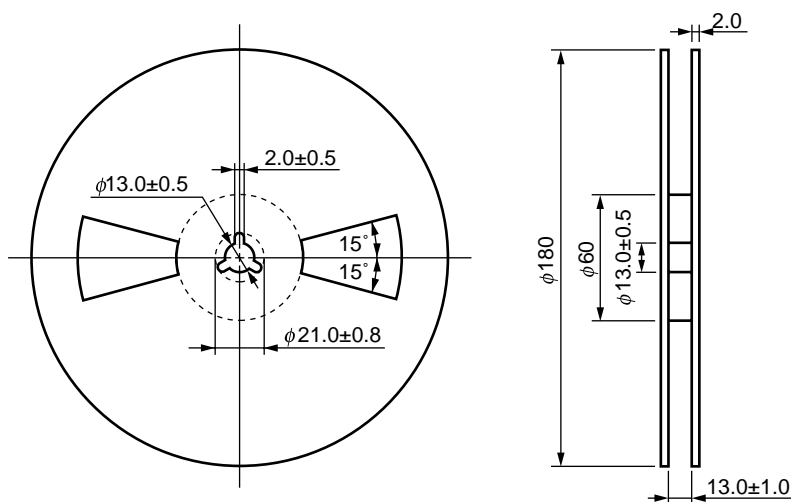
Outline and Dimensions (Tape)



Tape Direction



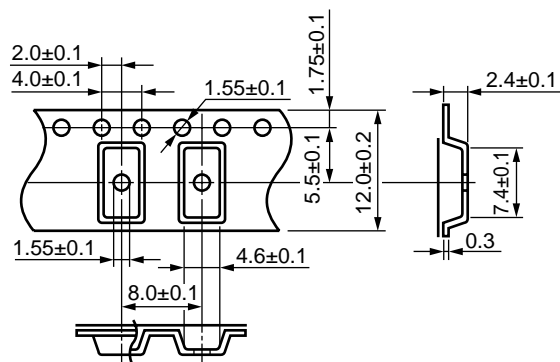
Outline and Dimensions (Reel)



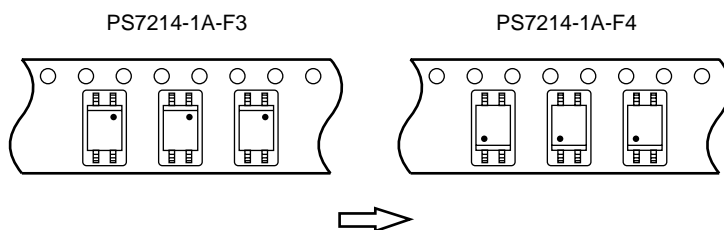
Packing: 900 pcs/reel



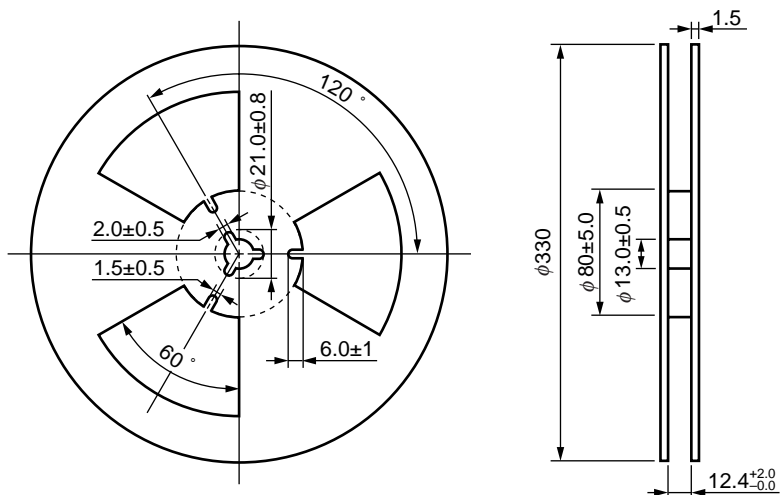
# Outline and Dimensions (Tape)



## Tape Direction



# Outline and Dimensions (Reel)



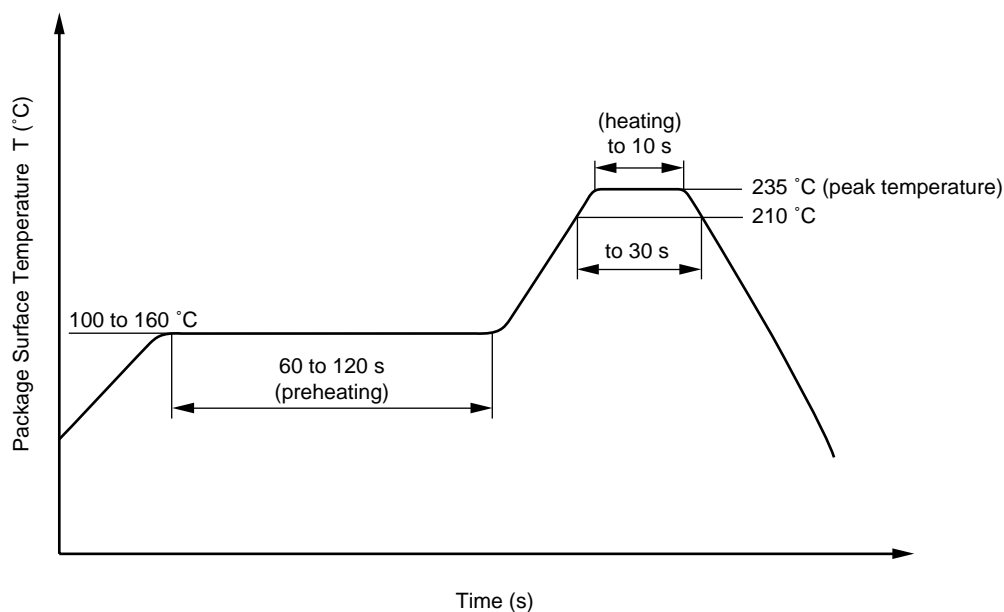
Packing: 3 500 pcs/reel

## ★ RECOMMENDED SOLDERING CONDITIONS

### (1) Infrared reflow soldering

- Peak reflow temperature 235 °C or below (package surface temperature)
- Time of temperature higher than 210 °C 30 seconds or less
- Number of reflows Two
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow



### (2) Dip soldering

- Temperature 260 °C or below (molten solder temperature)
- Time 10 seconds or less
- Number of times One
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

### (3) Cautions

- Fluxes
  - Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

[MEMO]

## CAUTION

**Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.**

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